## imall

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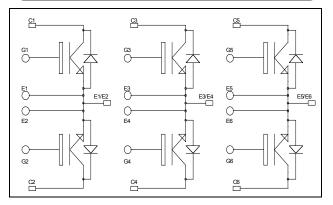
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#### Triple Dual Common Source Trench + Field Stop IGBT3 Power Module



#### 

#### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V <sub>CES</sub>	Collector - Emitter Breakdown Voltage		600	V
т	Continuous Collector Current	$T_C = 25^{\circ}C$	225	
I <sub>C</sub>	Continuous Conector Current	$T_C = 80^{\circ}C$	150	А
I <sub>CM</sub>	Pulsed Collector Current	$T_C = 25^{\circ}C$	350	
V <sub>GE</sub>	Gate – Emitter Voltage		±20	V
PD	Maximum Power Dissipation	$T_C = 25^{\circ}C$	480	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	300A @ 550V	

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$$V_{CES} = 600V$$
  
 $I_{C} = 150A$  @ Tc = 80°C

#### Application

- AC Switches
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

#### Features

- Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
  - Very low stray inductance
  - Symmetrical design
    - Lead frames for power connections
  - High level of integration

#### Benefits

- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Very low (12mm) profile
- Each leg can be easily paralleled to achieve a dual common source configuration of three times the current capability
- RoHS Compliant

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



#### All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

#### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I <sub>CES</sub>	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				250	μA
V <sub>CE(sat)</sub>	Collector Emitter Saturation Voltage	$V_{GE} = 15V$ $I_{C} = 150A$	$T_j = 25^{\circ}C$		1.5	1.9	V
			$T_{j} = 150^{\circ}C$		1.7		v
V <sub>GE(th)</sub>	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 1.5 \text{ mA}$		5.0	5.8	6.5	V
I <sub>GES</sub>	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

#### **Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		9200		
Coes	Output Capacitance	$V_{CE} = 25V$		580		pF
C <sub>res</sub>	Reverse Transfer Capacitance	f = 1 MHz		270		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (25°C)		115		ns
T <sub>r</sub>	Rise Time	$V_{GE} = \pm 15V$		45		
T <sub>d(off)</sub>	Turn-off Delay Time	$V_{Bus} = 300V$ $I_{C} = 150A$		225		
T <sub>f</sub>	Fall Time	$R_G = 3.3\Omega$		55		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (150°C)		130		ns
Tr	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 300V$		50		
T <sub>d(off)</sub>	Turn-off Delay Time	$I_{\rm C} = 150 \text{A}$		300		
$T_{\rm f}$	Fall Time	$R_G = 3.3\Omega$		70		
Б	Turn on Energy	$V_{GE} = \pm 15V$ $T_j = 25^{\circ}C$		0.85		mJ
Eon	Turn on Energy	$V_{Bus} = 300V$ $T_j = 150^{\circ}C$		1.5		1115
Б	Turn off Energy	$I_{\rm C} = 150 {\rm A}$ $T_{\rm j} = 25^{\circ} {\rm C}$		4.1		m I
E <sub>off</sub>	Turn off Energy	$R_G = 3.3\Omega$ $T_j = 150^{\circ}C$		5.3		mJ

#### Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage			600			V
I <sub>RM</sub>	Maximum Reverse Leakage Current	V <sub>R</sub> =600V	$T_i = 25^{\circ}C$ $T_i = 150^{\circ}C$			250 500	μA
I <sub>F</sub>	DC Forward Current		$T_i = 130 \text{ C}$ $T_c = 80^{\circ}\text{C}$		150	300	А
V	Diada Famuard Valtaga	$I_{\rm F} = 150 {\rm A}$ $V_{\rm GE} = 0 {\rm V}$	$T_i = 25^{\circ}C$		1.6	2	V
$V_{\rm F}$	Diode Forward Voltage		$T_{i} = 150^{\circ}C$		1.5		
+	Reverse Recovery Time		$T_j = 25^{\circ}C$		130		ng
t <sub>rr</sub>	Reverse Recovery Time		$T_{j} = 150^{\circ}C$		225		ns
0	Reverse Recovery Charge	$I_{\rm F} = 150 \text{A}$ $V_{\rm R} = 300 \text{V}$	$T_j = 25^{\circ}C$		6.9		uС
Q <sub>rr</sub>	Reverse Recovery Charge	$v_{\rm R} = 300 v$ di/dt = 3000 A/µs	$T_{j} = 150^{\circ}C$		14.5		μC
Er	D D France	] '	$T_j = 25^{\circ}C$		1.6		mI
	Reverse Recovery Energy		$T_{j} = 150^{\circ}C$		3.5	m	mJ

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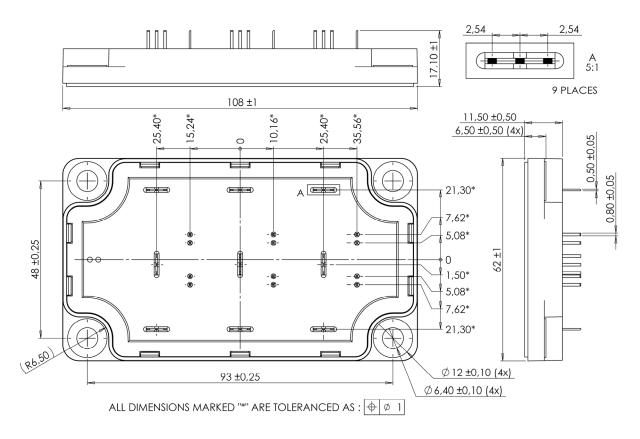


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#### Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R <sub>thJC</sub>	Junction to Case Thermal Resistance		IGBT			0.31	°C/W
			Diode			0.52	
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T <sub>J</sub>	Operating junction temperature range			-40		175	
T <sub>STG</sub>	Storage Temperature Range			-40		125	°C
T <sub>C</sub>	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Wt	Package Weight					250	g

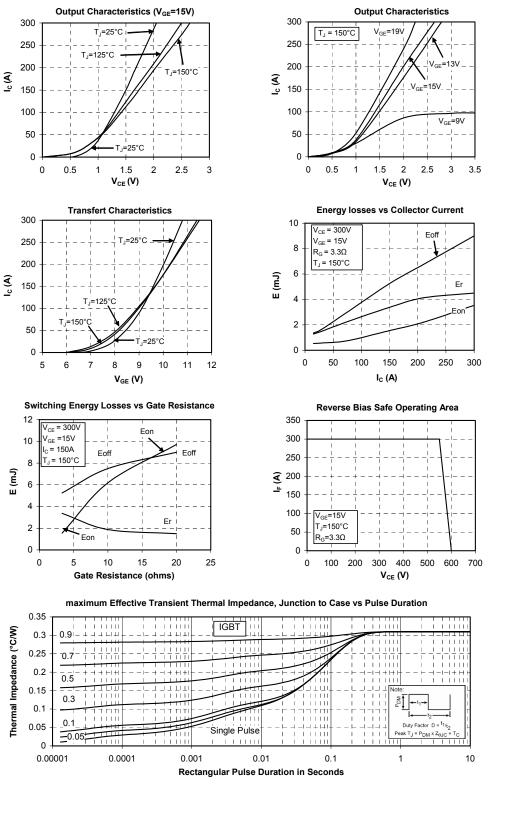
SP6-P Package outline (dimensions in mm)



See application note 1902 - Mounting Instructions for SP6-P (12mm) Power Modules on www.microsemi.com



#### **Typical Performance Curve**

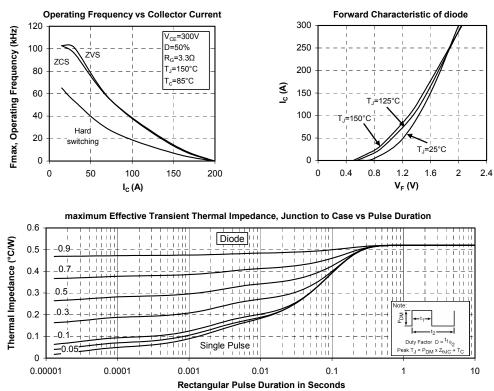


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